

# RC2 SPECIFICATIONS (6/4/2013)

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## Optical Configuration (along the light path)

Double-Rotating Compensator Ellipsometer:

- Source – Polarizer – Rotating Compensator – Sample – Rotating Compensator – Polarizer – Spectrometer

## Spectral Range

Model X: 210nm to 1000nm, 790 wavelengths

Model D: 190nm to 1000nm, 800 wavelengths

NIR extension: 1000nm to 1690nm, 275 wavelengths

## Spectral (Pixel) Resolution/Bandwidth

Model X, D: 1 nm wavelength spacing, 3nm bandwidth

NIR extension: 2.5 nm wavelength spacing, 5nm bandwidth

## Data Acquisition Rate

Complete acquisition cycle for SE or full MM data is 0.3 seconds.

For best signal-to-noise, measurements are averaged from 2-10 seconds at each angle.

## Beam Divergence

Less than 0.4°

## Beam Diameter

Standard beam is collimated with 3-4mm diameter.

With Focusing, two options are available:

- 40mm focal length lens:
  - Beam diameter (short direction) is less than 300 microns.
  - Maximum Angle of incidence is 75°
- 27mm focal length lens:
  - Beam diameter (short direction) is less than 200 microns.
  - Maximum Angle of incidence is 65°

## Components

Light Source:

Model X: 150W Xenon lamp

Model D: Combined Deuterium/Quartz-Tungsten Halogen lamps

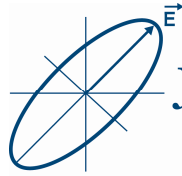
Compensators:

Patented achromatic design

Detector:

To 1000nm: 1024 pixel silicon CCD

1000-1690nm: 256 pixel InGaAs Array



## Measurement Quantities

Spectroscopic Ellipsometry:

$\Psi$  (0-90°) and  $\Delta$  (0-360°)

N,C, and S

Intensity:

%Transmission and %Reflection

Depolarization: %Depolarization

Generalized Ellipsometry\*:

AnE, Asp, and Aps (3 ratios of generalized Jones matrix)

Mueller Matrix\*:

All 15 normalized elements of the Mueller-matrix (normalized to m11).

*\*Useful for measuring and characterizing anisotropic materials with cross-polarization.*

## Straight-Through Accuracy

**(10 second measurement of empty-beam, met by 95% of all wavelengths)**

Psi:  $45^\circ \pm 0.02^\circ$

Delta:  $0^\circ \pm 0.05^\circ$

Depolarization:  $0\% \pm 0.5\%$

15 normalized Mueller-Matrix elements:

Diagonal:  $1 \pm 0.002$

Off-Diagonal:  $0 \pm 0.002$

## Off-Sample Data Fit Accuracy

**(10 second measurement of nominally 25nm SiO<sub>2</sub>/Si)**

MSE defined in terms of N,C,S < 0.002

MSE defined in terms of Mueller-matrix elements < 0.002

## Thickness Precision:

**(30 consecutive (static) 10-second measurements of nominally 25nm SiO<sub>2</sub>/Si)**

Standard deviation in thickness < 0.005 nm